·		2004/10/07	FPO: JPO:		9328	(BRS	S
. 0			USPAT; US-PGPUB;					
		12:03) 4) 4)	deposit\$5)) with (silicon or poly\$1) with (indium or lin or "ln")	272	14	BRS	4
		2004/10/07	USPAT; US-PGPUB;	(in-situ or insitu or (in adj situ)) with (CVD or (chemical adj vapor adj				
		11:54	IBM_TDB	or polysilicon or poly\$1) with indium				
	***************************************	****************	EPO; JPO;		10	L3	BRS	نن
				(silicon or polysilicon or poly\$1) with indium				
0	**************************************	2004/10/07 13:31		(chemical adj vapor adj deposit\$5)) with	0	L2	BRS	2
				(in-situ or insitu or (in adj situ)) with (CVD or	***************************************			
0		12:39	DERWENT; IBM_TDB	(silicon or poly or polysilicon)	25	L1	BRS	,
			USPAT; US-PGPUB;	indium adj doped adj2				
Error Er Definit ro ion rs	Comm	Time Stamp	DBs	Search Text	Hits	L #	Туре	

0	•		2004/10/07	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	InCl3 or "InCl3" or "InCl.sub.3" or "InCl.sub.3" Cl.sub.3"	968		BRS	
0		,	2004/10/07	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	indium adj (chloride\$1 or trichloride\$1 or tri-chloride\$1 or (tri adj chloride\$1))	969	L10 ,	BRS	10
0			2004/10/07 12:04	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	8 not 6	7	<u>.</u>	BRS	9
0			2004/10/07 12:04	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	7 and 5	24	L &	BRS	∞
0			2004/10/07 12:03	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	(in-situ or insitu or (in adj situ)) with (CVD or (chemical adj vapor adj deposit\$5)) with (indium or In or "In")	481	Ľ7	BRS	7
0	·		2004/10/07 11:59	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	4 and 5	17	16	BRS	6
ro rs	Error Definit ion	Comme nts	Time Stamp	DBs	Search Text	Hits	L #	Туре	

	Туре	L #	Hits	Search Text	DBs	Time Stamp	Comme 1	Error I Definit	ro
12	BRS	L12	1776	10 or 11	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:42			· ·
13	BRS	L ₁₃	2	(in-situ or insitu or (in adj situ)) with 12	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:44			0
14	BRS	L14	2913	(implant\$8 or dop\$4 or inject\$4 or introduc\$4) with (indium or In or "In") with (silicon or poly\$1 or polysilicon\$1 or poly-silicon\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:46	•		
15	BRS	L15	4670	14 and 5	B ;	2004/10/07 12:46			0
16	BRS	L16	149	15 and 12	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:47	•		

		Туре	# T	Hits	Search Text	DBs	Time Stamp	Comme nts	Error E Definit re
	17	BRS	L17 8	∞	14 same 12	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 12:48		
<u></u> ,	18	BRS	<u> </u>		(in-situ or insitu or (in adj situ)) same (silicon EPO; JPO; or polysilicon or poly\$1 DERWENT; or poly-silicon) same 12 IBM_TDB	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 13:56		
	19	BRS	L19	64	(in-situ or insitu or (in adj situ)) and (silicon or EPO; JPO; polysilicon or poly\$1 or DERWENT; poly-silicon) and 12 IBM_TDB	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 13:42		
	20	IS&R L20 1	L20		("20040000695").PN.	USPAT; US-PGPUB	2004/10/07 13:42		
	21	BRS	L21 3	3	16 and (in-situ or insitu or (in adj situ))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/07 13:56		